

TECHNICAL DATA

DATA SHEET 4135, REV. B PRELIMINARY

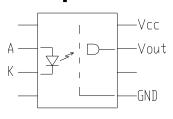
High Data Rate Optocoupler

Features:

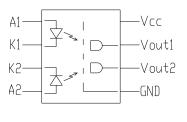
- Hermetic / Ceramic packages
- 60ns propagation delay
- 40Mbd Typical Signal Rate
- Low Input Current (1.6mA to 1.8mA)
- CMOS Output

Applications:

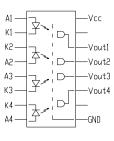
- High Speed Isolation
- Ground Loop Elimination
- Pulse Transformer Replacement
- A/D, D/A Conversion
- Switching Power Supplies



-211 (DIP)



-221 (DIP)



-241 (DIP)

Absolute Maximum Ratings

PARAMETER		SYMBOL	RATING	UNIT
Input	Forward Current	I _F	10	mA
	Peak Forward Current	I _{FM}	25	mA
	Reverse Voltage	V _R	6	V
Output	Supply Voltage	$V_{\sf CEO}$	0 to 7	V
	Output Voltage	V _{ECO}	5 to 10	V
	Current	I _C	25	mA
	Total Power Dissipation	P _C	P _C 200	
Isolation Voltage**		V _{iso}	5000	V_{rms}
Operating Temperature		T_{opr}	-55 to +125	°C
Storage Temperature		T _{stg}	-55 to +150	°C
Soldering Temperature		T _{sol}	260	°C

^{* &}lt; 1 ms duration</p>

^{**} AC for 1 min, 40 to 60% RH

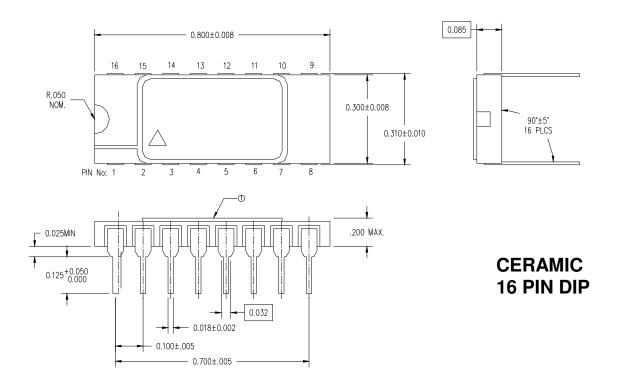
^{***} For 10 seconds

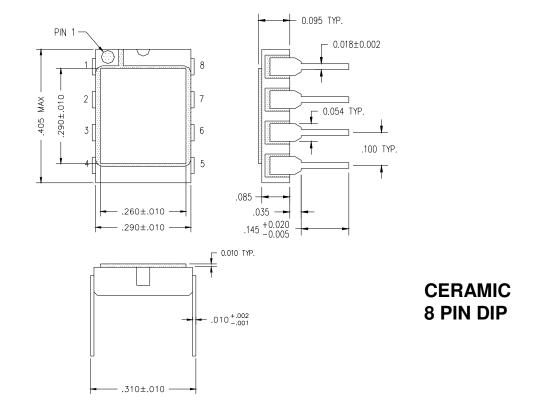


Electro-Optical Characteristics (-55° to 125°C)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Forward Voltage	V _F	I _F = 1 mA	-	1.1	1.4	V
Reverse Current	I _R	V _R = 4 V	-	-	12	μА
Reverse Breakdown Voltage	BV _R	I _R =15 μA	6	-	-	V
Logic Low Output Voltage	V _{OL}	I _{OL} = 5 mA	-	-	0.5	V
Logic High Output Voltage	V _{OH}	I _{OH} = -2.5 mA	2.4	-	-	V
Isolation Resistance	R _{ISO}	500 V _{DC} , 40–60% RH	4x10 ¹⁰	10 ¹¹	-	Ω
Floating Capacitance	C _F	f = 1MHz	-	0.6	1.0	pF
Supply Current, low (per device)	I _{SL}	I _F =0mA, V _{CC} =20V	-	-	23	mA
Supply Current, high (per device)	I _{SH}	I _F =5mA, V _{CC} =20V	-	-	21	mA
Propagation Delay, low to high	t _{LH}	-	-	-	60	ns
Propagation Delay, high to low	t _{HL}	-	-	-	60	ns
Rise Time	t _r	-	-	20	-	ns
Fall Time	t _f	-	-	10	-	ns









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